

Automotive door actuator driver with embedded LIN

Data brief



Features



- 1 half bridge for 7.5 A load ($R_{ON} = 100 \text{ m}\Omega$)
 - 1 half bridge for 7.5 A load ($R_{ON} = 150 \text{ m}\Omega$)
 - 2 half bridges for 3 A load ($R_{ON} = 300 \text{ m}\Omega$)
 - 1 configurable high-side driver for up to 1.5 A ($R_{ON} = 500 \text{ m}\Omega$) or 0.35 A ($R_{ON} = 1600 \text{ m}\Omega$) load
 - 1 configurable high-side driver for 0.8 A ($R_{ON} = 800 \text{ m}\Omega$) or 0.35 A ($R_{ON} = 1600 \text{ m}\Omega$) load
 - 3 configurable high-side drivers for 0.15 A/0.35 A ($R_{ON} = 2 \text{ }\Omega$)
 - 1 configurable high-side driver for 0.25 A/0.5 A ($R_{ON} = 2 \text{ }\Omega$)
 - 4 configurable high-side drivers for 0.15 A/0.25 A ($R_{ON} = 5 \text{ }\Omega$)
 - Internal 10bit PWM timer for each stand-alone high-side driver
 - Buffered supply for voltage regulators and 2 high-side drivers (OUT15 & OUT_HS / both P-channel) to supply e.g. external contacts
 - Programmable soft-start function to drive loads with higher inrush currents as current limitation value (for OUT1-6, OUT7, OUT8 and OUT_HS) with thermal expiration feature
 - All the embedded outputs come with protection and supervision features:
 - Current Monitor (high-side only)
 - Open-load
 - Overcurrent
 - Thermal warning
 - Thermal shutdown
- Fully protected driver for external MOSFETs in H-bridge configuration
 - Two 5 V voltage regulators for microcontroller and peripheral supply
 - Programmable reset generator for power-on and undervoltage
 - Configurable window watchdog
 - LIN 2.2a compliant (SAEJ2602 compatible) transceiver
 - Separated (Isolated) fail-safe block with 2 LS ($R_{ON} = 1 \text{ }\Omega$) to pull down the gates of the external HS MOSFETs
 - Thermal clusters
 - A/D conversion of supply voltages and internal temperature sensors
 - Embedded and programmable VS duty cycle adjustment for LED driver outputs

Description

The L99DZ120 is a door zone systems IC providing electronic control modules with enhanced power management power supply functionality, including various standby modes, as well as LIN physical communication layers.

The two low-drop voltage regulators of the devices supply the system microcontroller and external peripheral loads such as sensors and provide enhanced system standby functionality with programmable local and remote wake-up capability. In addition 8 high-side drivers to supply LEDs, 2 high-side drivers to supply bulbs increase the system integration level.

Up to 3 DC motors and 4 external MOS transistors in H-bridge configuration can be driven. All outputs are SC protected and implement an open-load diagnosis.

The ST standard SPI interface (4.0) allows control and diagnosis of the device and enables generic software development.

1 Block diagram and pin descriptions

Figure 1. Block diagram

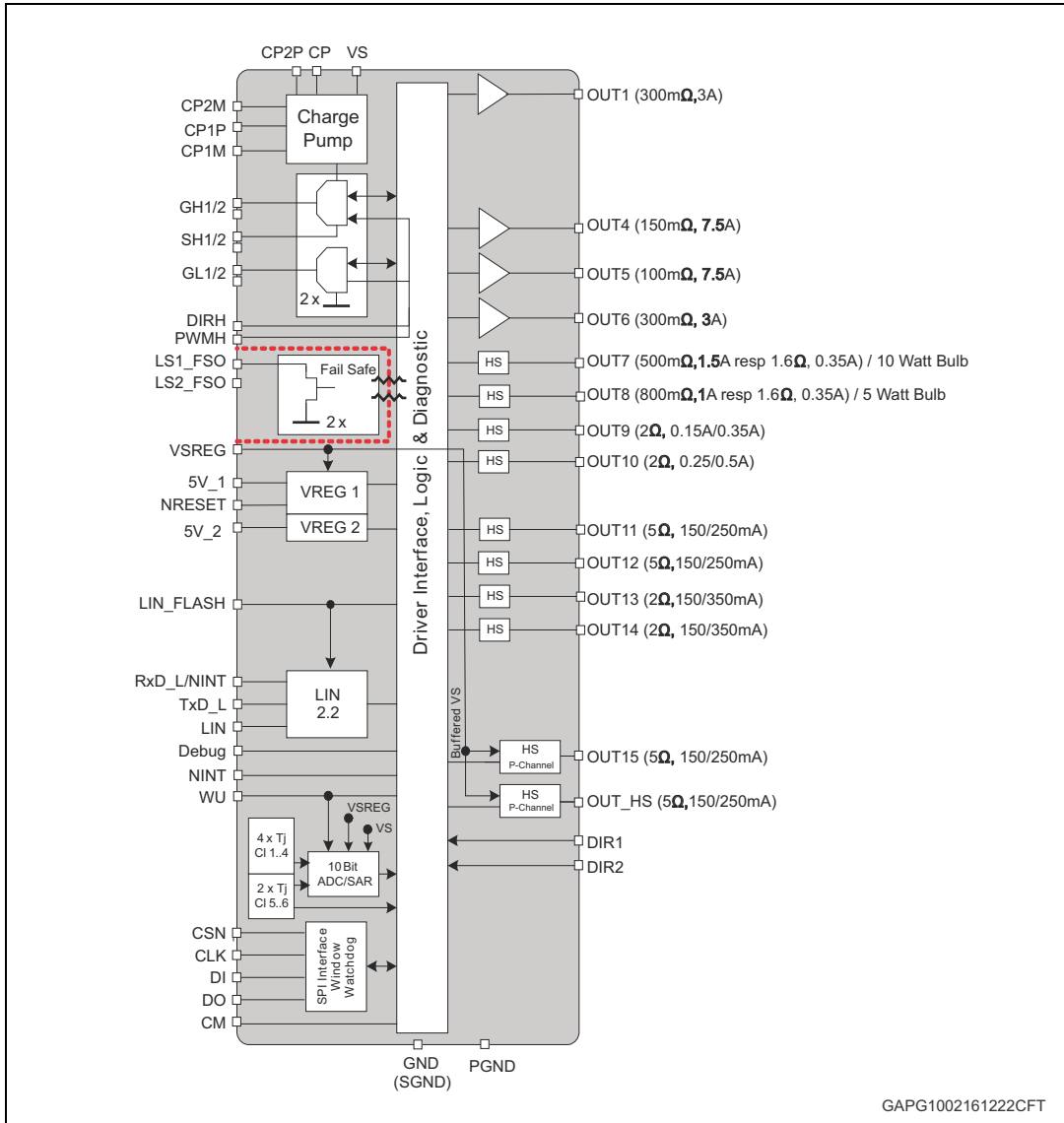


Table 1. Pin definitions and functions

Pin	Symbol	Function
1	WU	Wake-up Input: Input pin for static or cyclic monitoring of external contacts
2	CP2M	Charge pump pin for capacitor 2, negative side
3	CP2P	Charge pump pin for capacitor 2, positive side
4	CP	Charge pump output
5	CP1P	Charge pump pin for capacitor 1, positive side
6	CP1M	Charge pump pin for capacitor 1, negative side

Table 1. Pin definitions and functions (continued)

Pin	Symbol	Function
7	NC	Not connected
8	NC	Not connected
9	OUT14	High-side-driver output to drive LEDs
10	OUT13	High-side-driver output to drive LEDs
11	OUT12	High-side-driver output to drive LEDs
12	OUT9	High-side-driver output to drive LEDs
13	OUT10	High-side-driver-output
14	OUT11	High-side-driver output to drive LEDs
15	LS1_FSO	Fail Safe low-side switch (Active low)
16	LS2_FSO	Fail Safe low-side switch (Active low)
17	VS	Power supply voltage for power stage outputs (external reverse battery protection required), for this input a ceramic capacitor as close as possible to GND is recommended. Important: For the capability of driving, the full current at the outputs all pins of VS must be connected externally!
18	VS; 2nd pin	Current capability (pin description see above)
19	OUT7	High-side-driver output to drive LEDs or a 10 Watt bulb (programmable R_{dson})
20	OUT6	Half-bridge outputs: the output is built by a high-side and a low-side switch which are internally connected. The output stage of both switches is a power DMOS transistor. Each driver has an internal parasitic reverse diode (bulk-drain-diode: high-side driver from output to VS, low-side driver from GND to output)
21	OUT1	Half-bridge outputs: the output is built by a high-side and a low-side switch which are internally connected. The output stage of both switches is a power DMOS transistor. Each driver has an internal parasitic reverse diode (bulk-drain-diode: high-side driver from output to VS, low-side driver from GND to output)
22	NC	Not connected
23	OUT5	Half-bridge outputs: the output is built by a high-side and a low-side switch which are internally connected. The output stage of both switches is a power DMOS transistor. Each driver has an internal parasitic reverse diode (bulk-drain-diode: high-side driver from output to V_S , low-side driver from GND to output)
24	OUT5; 2nd pin	Current capability (pin description see above)
25	V_{SREG}	Power supply voltage to supply the internal voltage regulators, OUT15 and the OUT_HS (external reverse battery protection required / Diode) for this input a ceramic capacitor as close as possible to GND and an electrolytic back up capacitor is recommended.
26	OUT_HS	High-side-driver output to drive LEDs or to supply contacts

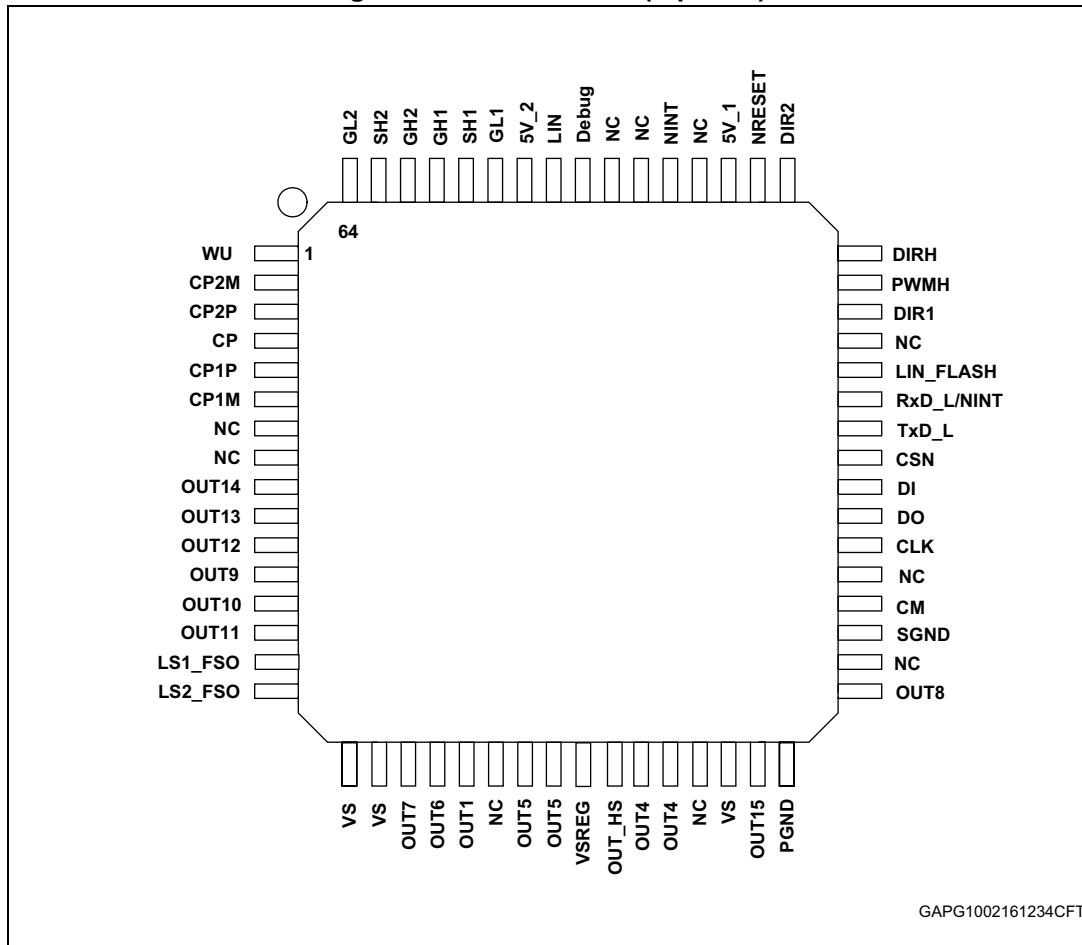
Table 1. Pin definitions and functions (continued)

Pin	Symbol	Function
27	OUT4	Half-bridge outputs: the output is built by a high-side and a low-side switch which are internally connected. The output stage of both switches is a power DMOS transistor. Each driver has an internal parasitic reverse diode (bulk-drain-diode: high-side driver from output to V_S , low-side driver from GND to output)
28	OUT4; 2 nd pin	Current capability (pin description see above)
29	NC	Not connected
30	VS; 3rd pin	Current capability (for the pin description see above)
31	OUT15	High-side-driver output to drive LEDs
32	PGND	Power GND
33	OUT8	High-side-driver output to drive LEDs or a 5 Watt bulb (programmable R_{dson})
34	NC	Not connected
35	SGND	Signal Ground
36	CM	Current monitor output: depending on the selected multiplexer bits CM_SEL_x (CR 7) of the; Control Register this output sources an image of the instant current; through the corresponding high-side driver with a fixed ratio
37	NC	Not connected
38	CLK	SPI: serial clock input
39	DO	SPI: serial data output (push pull output stage)
40	DI	SPI: serial data input
41	CSN	SPI: chip select not input
42	TxD_L	LIN Transmit data input
43	RxD_L/NINT	RxDL -> LIN receive data output; NINT -> indicates local/remote wake-up events (push pull output stage)
44	LIN_FLASH	LIN Flash Mode enable (former TxD_C pin, to guarantee family compatibility)
45	NC	Not connected
46	DIR1	Direct Drive Input 1
47	PWMH	PWMH input: this input signal can be used to control the H-bridge Gate Drivers.
48	DIRH	Direction Input: this input controls the H-bridge Drivers for the external MOSFETs
49	DIR2	Direct Drive Input 2
50	NRESET	NReset output to micro controller; (reset state = LOW) (low-side switch with drain connected to the output pin and internal pull up resistance to 5V_1)
51	5V_1	Voltage regulator 1 output: 5 V supply e.g. micro controller
52	NC	Not connected

Table 1. Pin definitions and functions (continued)

Pin	Symbol	Function
53	NINT	Interrupt output (low active; push-pull output stage) to indicate V_{SREG} early warning (Active mode); indicates wake-up events from V1_standby mode
54	NC	Not connected
55	NC	Not connected
56	Debug	Debug input to deactivate the window watchdog (high active)
57	LIN	LIN bus line
58	5V_2	Voltage regulator 2 output: 5 V supply for external loads (potentiometer, sensors). V2 is protected against reverse supply
59	GL1	Gate driver for PowerMOS low-side switch in half-bridge 1
60	SH1	Source of high-side switch in half-bridge 1
61	GH1	Gate driver for PowerMOS high-side switch in half-bridge 1
62	GH2	Gate driver for PowerMOS high-side switch in half-bridge 2
63	SH2	Source of high-side switch in half-bridge 2
64	GL2	Gate driver for PowerMOS low-side switch in half-bridge 2

Figure 2. Pin connection (top view)



2 Revision history

Table 2. Document revision history

Date	Revision	Changes
03-Nov-2016	1	Initial release.

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